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# **LNA2W01L** (LN57)

### GaAs Infrared Light Emitting Diode

For optical control systems

#### ■ Features

- High-power output, high-efficiency:  $P_O = 4.5 \text{ mW (typ.)}$
- Emitted light spectrum suited for silicon photodetectors
- Infrared light emission close to monochromatic light:  $\lambda_P = 950 \text{ nm}$  (typ.)
- Wide directivity:  $\theta = 18^{\circ}$  (typ.)
- Ultra-miniature double ended package

#### ■ Absolute Maximum Ratings $T_a = 25$ °C

| Parameter                     | Symbol           | Rating      | Unit |  |
|-------------------------------|------------------|-------------|------|--|
| Power dissipation             | P <sub>D</sub>   | 75          | mW   |  |
| Forward current               | I <sub>F</sub>   | 50          | mA   |  |
| Pulse forward current *       | $I_{FP}$         | 1           | A    |  |
| Reverse voltage               | $V_R$            | 3           | V    |  |
| Operating ambient temperature | Topr             | -25 to +85  | °C   |  |
| Storage temperature           | T <sub>stg</sub> | -30 to +100 | °C   |  |

Note) \*: f = 100 Hz, Duty cycle = 0.1%

#### ■ Electrical-Optical Characteristics $T_a = 25$ °C±3°C

| Parameter                | Symbol           | Conditions                                  | Min | Тур  | Max  | Unit |
|--------------------------|------------------|---|-----|------|------|------|
| Radiant power *          | P <sub>O</sub>   | $I_F = 50 \text{ mA}$                       | 3.0 | 4.5  | 3    | mW   |
| Reverse current          | $I_R$            | $V_R = 3 V$                                 |     |      | 10   | μА   |
| Forward voltage          | $V_{\rm F}$      | $I_F = 50 \text{ mA}$                       |     | 1.25 | 1.50 | V    |
| Terminal capacitance     | $C_{t}$          | $V_R = 0 V, f = 1 MHz$                      | 200 | 35   |      | pF   |
| Peak emission wavelength | $\lambda_{ m P}$ | $I_F = 50 \text{ mA}$                       | 2   | 950  |      | nm   |
| Spectral half band width | Δλ               | $I_F = 50 \text{ mA}$                       |     | 50   |      | nm   |
| Half-power angle         | θ                | The angle when the radiant power is halved. |     | 18   |      | 0    |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

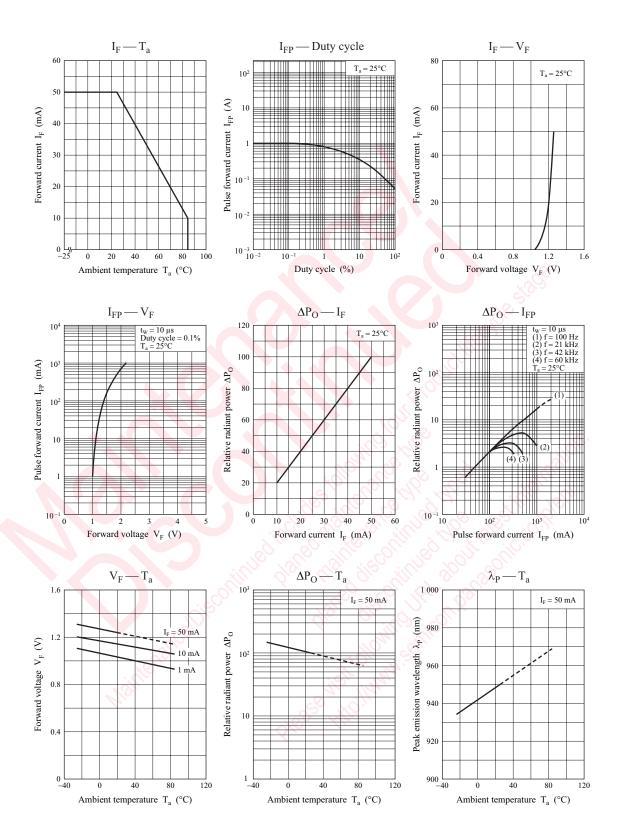
2. Cutoff frequency: 1 MHz

$$f_C: 10 \times \log \frac{P_O \text{ at } f = f_C}{P_O \text{ at } f = 50 \text{ kHz}} = -3$$

3. \*: A light detection element uses a silicon diode have proofread a load with a standard device.

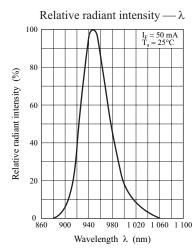
LNA2W01L

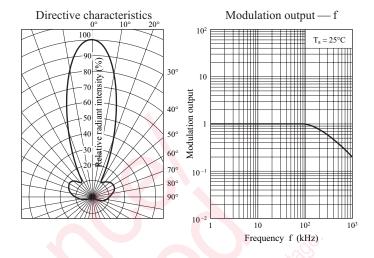
### **Panasonic**



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Panasonic LNA2W01L

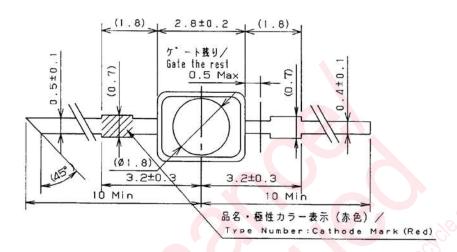


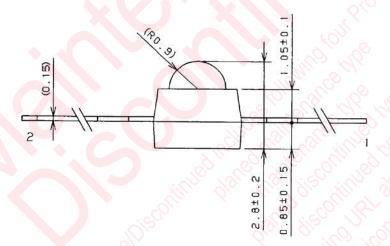


LNA2W01L Panasonic

■ Package (Unit: mm)

## LETLTN2S0001







- Pin name
  - 1: Anode
  - 2: Cathode

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